

# MIC4421/4422

9A-Peak Low-Side MOSFET Driver

### **Bipolar/CMOS/DMOS Process**

## **General Description**

MIC4421 and MIC4422 MOSFET drivers are rugged, efficient, and easy to use. The MIC4421 is an inverting driver, while the MIC4422 is a non-inverting driver.

Both versions are capable of 9A (peak) output and can drive the largest MOSFETs with an improved safe operating margin. The MIC4421/4422 accepts any logic input from 2.4V to  $V_s$  without external speed-up capacitors or resistor networks. Proprietary circuits allow the input to swing negative by as much as 5V without damaging the part. Additional circuits protect against damage from electrostatic discharge.

MIC4421/4422 drivers can replace three or more discrete components, reducing PCB area requirements, simplifying product design, and reducing assembly cost.

Modern Bipolar/CMOS/DMOS construction guarantees freedom from latch-up. The rail-to-rail swing capability of CMOS/DMOS insures adequate gate voltage to the MOS-FET during power up/down sequencing. Since these devices are fabricated on a self-aligned process, they have very low crossover current, run cool, use little power, and are easy to drive.

### Features

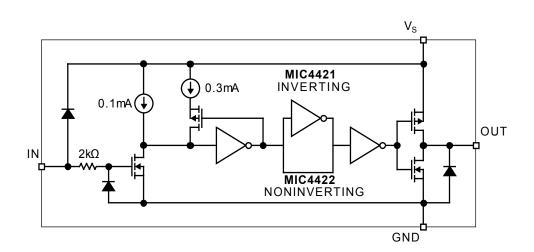
- BiCMOS/DMOS Construction
- Latch-Up Proof: Fully Isolated Process is Inherently Immune to Any Latch-up.
- Input Will Withstand Negative Swing of Up to 5V
- Matched Rise and Fall Times ...... 25ns

- Logic High Input for Any Voltage from 2.4V to  $\rm V_s$
- Low Equivalent Input Capacitance (typ)......7pF
- Low Supply Current ...... 450µA With Logic 1 Input
- Low Output Impedance ......1.5 $\Omega$
- Output Voltage Swing to Within 25mV of GND or  $\rm V_s$

### Applications

- Switch Mode Power Supplies
- Motor Controls
- Pulse Transformer Driver
- Class-D Switching Amplifiers
- Line Drivers
- Driving MOSFET or IGBT Parallel Chip Modules
- Local Power ON/OFF Switch
- Pulse Generators

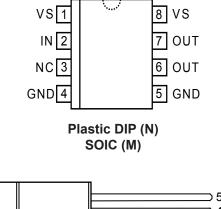
### **Functional Diagram**



# **Ordering Information**

| Part Number |           |               |                |              |
|-------------|-----------|---------------|----------------|--------------|
| Standard    | PbFree    | Configuration | Temp. Range    | Package      |
| MIC4421BM   | MIC4421YM | Inverting     | -40°C to +85°C | 8-pin SOIC   |
| MIC4421BN   | MIC4421YN | Inverting     | –40°C to +85°C | 8-pin DIP    |
| MIC4421CM   | MIC4421ZM | Inverting     | –0°C to +70°C  | 8-pin SOIC   |
| MIC4421CN   | MIC4421ZN | Inverting     | –0°C to +70°C  | 8-pin DIP    |
| MIC4421CT   | MIC4421ZT | Inverting     | –0°C to +70°C  | 5-pin TO-220 |
| MIC4422BM   | MIC4422YM | Non-inverting | –40°C to +85°C | 8-pin SOIC   |
| MIC4422BN   | MIC4422YN | Non-inverting | –40°C to +85°C | 8-pin DIP    |
| MIC4422CM   | MIC4422ZM | Non-inverting | –0°C to +70°C  | 8-pin SOIC   |
| MIC4422CN   | MIC4422ZN | Non-inverting | –0°C to +70°C  | 8-pin DIP    |
| MIC4422CT   | MIC4422ZT | Non-inverting | –0°C to +70°C  | 5-pin TO-220 |

# **Pin Configurations**





TO-220-5 (T)

# **Pin Description**

| Pin Number<br>TO-220-5 | Pin Number<br>DIP, SOIC | Pin Name       | Pin Function  |  |
|------------------------|-------------------------|----------------|---|--|
| 1                      | 2                       | IN             | Control Input   |  |
| 2, 4                   | 4, 5                    | GND            | Ground: Duplicate pins must be externally connected together.       |  |
| 3, тав                 | 1, 8                    | V <sub>s</sub> | Supply Input: Duplicate pins must be externally connected together. |  |
| 5                      | 6, 7                    | OUT            | Output: Duplicate pins must be externally connected together.       |  |
|                        | 3                       | NC             | Not connected.  |  |

| Absolute Maximum Ratings (Notes 1, 2 and 3)   |
|---|
| Supply Voltage20V                             |
| Input Voltage $V_s$ + 0.3V to GND – 5V        |
| Input Current ( $V_{IN} > V_{S}$ )            |
| Power Dissipation, $T_A \le 25^{\circ}C$      |
| PDIP  |
| SOIC 1040mW                                   |
| 5-Pin TO-2202W                                |
| Power Dissipation, $T_{CASE} \le 25^{\circ}C$ |
| 5-Pin TO-220 12.5W                            |
| Derating Factors (to Ambient)                 |
| PDIP7.7mW/°C                                  |
| SOIC8.3mW/°C                                  |
| 5-Pin TO-220 17mW/°C                          |
| Storage Temperature65°C to +150°C             |
| Lead Temperature (10 sec) 300°C               |

| Operating Ratings            |                |  |  |  |
|------------------------------|----------------|--|--|--|
| Junction Temperature         | 150°C          |  |  |  |
| Ambient Temperature          |                |  |  |  |
| C Version                    | 0°C to +70°C   |  |  |  |
| B Version                    | –40°C to +85°C |  |  |  |
| Thermal Resistance           |                |  |  |  |
| 5-Pin TO-220 $(\theta_{JC})$ | 10°C/W         |  |  |  |

# **Electrical Characteristics:** ( $T_A = 25^{\circ}C$ with $4.5 V \le V_s \le 18 V$ unless otherwise specified.)

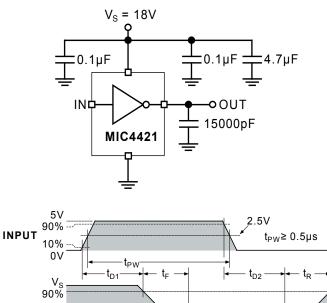
| Symbol          | Parameter  | Conditions                                      | Min                  | Тур       | Max                 | Units    |
|-----------------|--|---|----------------------|-----------|---------------------|----------|
| INPUT           |  |   |                      |           |                     |          |
| V <sub>IH</sub> | Logic 1 Input Voltage                            |   | 2.4                  | 1.3       |                     | V        |
| V <sub>IL</sub> | Logic 0 Input Voltage                            |   |                      | 1.1       | 0.8                 | V        |
| V <sub>IN</sub> | Input Voltage Range                              |   | -5                   |           | V <sub>s</sub> +0.3 | V        |
| I <sub>IN</sub> | Input Current                                    | $0 V \le V_{IN} \le V_{S}$                      | -10                  |           | 10                  | μA       |
| OUTPUT          | 1  | 1   | I                    |           |                     |          |
| V <sub>OH</sub> | High Output Voltage                              | See Figure 1                                    | V <sub>s</sub> –.025 |           |                     | V        |
| V <sub>OL</sub> | Low Output Voltage                               | See Figure 1                                    |                      |           | 0.025               | V        |
| R <sub>o</sub>  | Output Resistance,<br>Output High                | I <sub>OUT</sub> = 10 mA, V <sub>s</sub> = 18 V |                      | 0.6       |                     | Ω        |
| R <sub>o</sub>  | Output Resistance,<br>Output Low                 | I <sub>OUT</sub> = 10 mA, V <sub>s</sub> = 18 V |                      | 0.8       | 1.7                 | Ω        |
| I <sub>PK</sub> | Peak Output Current                              | V <sub>s</sub> = 18 V (See Figure 6)            |                      | 9         |                     | A        |
| I <sub>DC</sub> | Continuous Output Current                        |   | 2                    |           |                     | A        |
| I <sub>R</sub>  | Latch-Up Protection<br>Withstand Reverse Current | Duty Cycle ≤ 2%<br>t ≤ 300 µs                   | >1500                |           |                     | mA       |
| SWITCHIN        | G TIME (Note 3)                                  | ł   |                      |           | 1                   |          |
| t <sub>R</sub>  | Rise Time  | Test Figure 1, C <sub>L</sub> = 10,000 pF       |                      | 20        | 75                  | ns       |
| t <sub>F</sub>  | Fall Time  | Test Figure 1, C <sub>L</sub> = 10,000 pF       |                      | 24        | 75                  | ns       |
| t <sub>D1</sub> | Delay Time                                       | Test Figure 1                                   |                      | 15        | 60                  | ns       |
| t <sub>D2</sub> | Delay Time                                       | Test Figure 1                                   |                      | 35        | 60                  | ns       |
| POWER SI        | JPPLY  |   | I                    |           |                     |          |
| I <sub>s</sub>  | Power Supply Current                             | $V_{\rm IN} = 3 V$ $V_{\rm IN} = 0 V$           |                      | 0.4<br>80 | 1.5<br>150          | mA<br>μA |
| V <sub>s</sub>  | Operating Input Voltage                          |   | 4.5                  |           | 18                  | V        |
|                 |  |   |                      |           |                     |          |

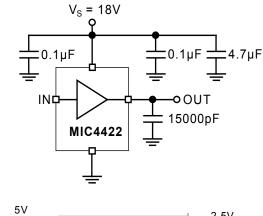
| Symbol          | Parameter                         | Conditions                                    | Min                | Тур        | Max                 | Units    |
|-----------------|-----------------------------------|---|--------------------|------------|---------------------|----------|
| INPUT           |                                   |   |                    |            |                     | I        |
| V <sub>IH</sub> | Logic 1 Input Voltage             |   | 2.4                | 1.4        |                     | V        |
| V <sub>IL</sub> | Logic 0 Input Voltage             |   |                    | 1.0        | 0.8                 | V        |
| V <sub>IN</sub> | Input Voltage Range               |   | -5                 |            | V <sub>s</sub> +0.3 | V        |
| I <sub>IN</sub> | Input Current                     | $0V \le V_{IN} \le V_{S}$                     | -10                |            | 10                  | μA       |
| OUTPUT          | ·                                 | ·   |                    |            | •                   |          |
| V <sub>oh</sub> | High Output Voltage               | Figure 1                                      | V <sub>s</sub> 025 |            |                     | V        |
| V <sub>ol</sub> | Low Output Voltage                | Figure 1                                      |                    |            | 0.025               | V        |
| R <sub>o</sub>  | Output Resistance,<br>Output High | I <sub>OUT</sub> = 10mA, V <sub>s</sub> = 18V |                    | 0.8        | 3.6                 | Ω        |
| R <sub>o</sub>  | Output Resistance,<br>Output Low  | I <sub>OUT</sub> = 10mA, V <sub>s</sub> = 18V |                    | 1.3        | 2.7                 | Ω        |
| SWITCHIN        | G TIME (Note 3)                   |   | <u>I</u> <u>I</u>  |            | <u>.</u>            | <u> </u> |
| t <sub>R</sub>  | Rise Time                         | Figure 1, C <sub>L</sub> = 10,000pF           |                    | 23         | 120                 | ns       |
| t <sub>F</sub>  | Fall Time                         | Figure 1, C <sub>L</sub> = 10,000pF           |                    | 30         | 120                 | ns       |
| t <sub>D1</sub> | Delay Time                        | Figure 1                                      |                    | 20         | 80                  | ns       |
| t <sub>D2</sub> | Delay Time                        | Figure 1                                      |                    | 40         | 80                  | ns       |
| POWER S         | UPPLY                             |   |                    |            |                     |          |
| l <sub>s</sub>  | Power Supply Current              | V <sub>IN</sub> = 3V<br>V <sub>IN</sub> = 0V  |                    | 0.6<br>0.1 | 3<br>0.2            | mA       |
| V <sub>s</sub>  | Operating Input Voltage           |   | 4.5                |            | 18                  | V        |

**Note 2:** Static-sensitive device. Store only in conductive containers. Handling personnel and equipment should be grounded to prevent damage from static discharge.

**Note 3:** Switching times guaranteed by design.

# **Test Circuits**





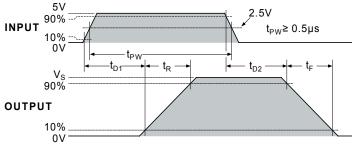


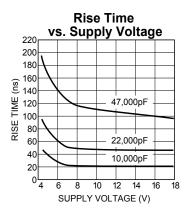
Figure 1. Inverting Driver Switching Time

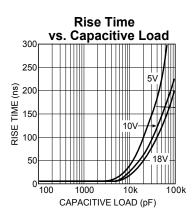


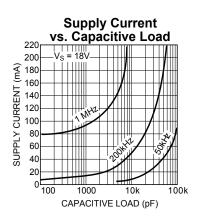
10% 0V

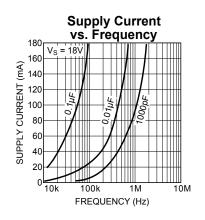
OUTPUT

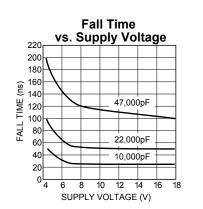
# **Typical Characteristics**

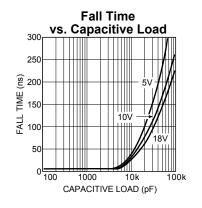


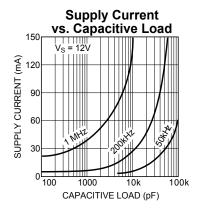


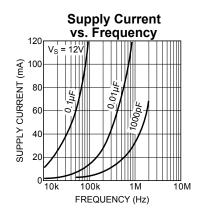


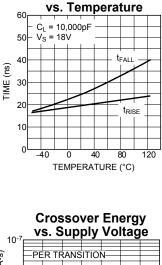




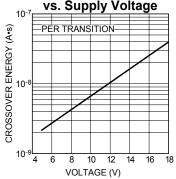


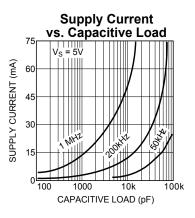


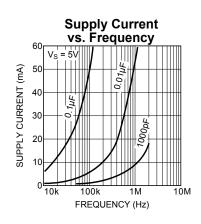




**Rise and Fall Times** 

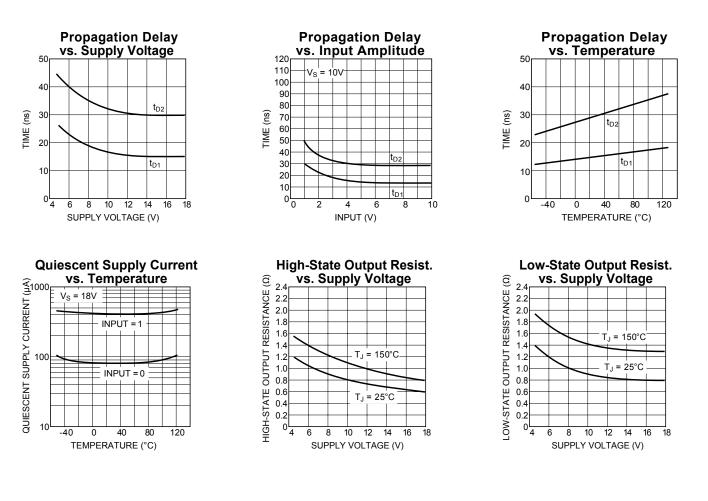








# **Typical Characteristics**



# **Applications Information**

### Supply Bypassing

Charging and discharging large capacitive loads quickly requires large currents. For example, charging a 10,000pF load to 18V in 50ns requires 3.6A.

The MIC4421/4422 has double bonding on the supply pins, the ground pins and output pins. This reduces parasitic lead inductance. Low inductance enables large currents to be switched rapidly. It also reduces internal ringing that can cause voltage breakdown when the driver is operated at or near the maximum rated voltage.

Internal ringing can also cause output oscillation due to feedback. This feedback is added to the input signal since it is referenced to the same ground.

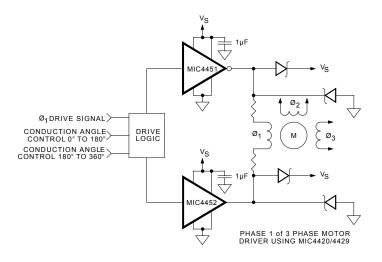


Figure 3. Direct Motor Drive

To guarantee low supply impedance over a wide frequency range, a parallel capacitor combination is recommended for supply bypassing. Low inductance ceramic disk capacitors with short lead lengths (< 0.5 inch) should be used. A 1µF low ESR film capacitor in parallel with two 0.1µF low ESR ceramic capacitors, (such as AVX RAM Guard®), provides adequate bypassing. Connect one ceramic capacitor directly between pins 1 and 4. Connect the second ceramic capacitor directly between pins 8 and 5.

#### Grounding

The high current capability of the MIC4421/4422 demands careful PC board layout for best performance. Since the MIC4421 is an inverting driver, any ground lead impedance will appear as negative feedback which can degrade switching speed. Feedback is especially noticeable with slow-rise time inputs. The MIC4421 input structure includes about 200mV of hysteresis to ensure clean transitions and freedom from oscillation, but attention to layout is still recommended.

Figure 5 shows the feedback effect in detail. As the MIC4421 input begins to go positive, the output goes negative and several amperes of current flow in the ground lead. As little as  $0.05\Omega$  of PC trace resistance can produce hundreds of millivolts at the MIC4421 ground pins. If the driving logic is referenced to power ground, the effective logic input level is reduced and oscillation may result.

To insure optimum performance, separate ground traces should be provided for the logic and power connections. Connecting the logic ground directly to the MIC4421 GND pins will ensure full logic drive to the input and ensure fast output switching. Both of the MIC4421 GND pins should, however, still be connected to power ground.

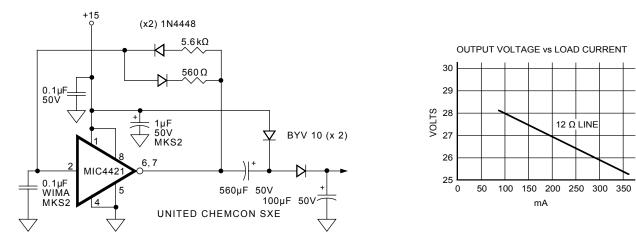


Figure 4. Self Contained Voltage Doubler

#### Input Stage

The input voltage level of the MIC4421 changes the quiescent supply current. The N channel MOSFET input stage transistor drives a 320µA current source load. With a logic "1" input, the maximum quiescent supply current is 400µA. Logic "0" input level signals reduce quiescent current to 80µA typical.

The MIC4421/4422 input is designed to provide 300mV of hysteresis. This provides clean transitions, reduces noise sensitivity, and minimizes output stage current spiking when changing states. Input voltage threshold level is approximately 1.5V, making the device TTL compatible over the full temperature and operating supply voltage ranges. Input current is less than  $\pm 10\mu$ A.

The MIC4421 can be directly driven by the TL494, SG1526/1527, SG1524, TSC170, MIC38C42, and similar switch mode power supply integrated circuits. By offloading the power-driving duties to the MIC4421/4422, the power supply controller can operate at lower dissipation. This can improve performance and reliability.

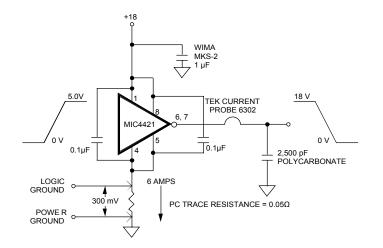
The input can be greater than the V<sub>s</sub> supply, however, current will flow into the input lead. The input currents can be as high as 30mA p-p ( $6.4mA_{RMS}$ ) with the input. No damage will occur to MIC4421/4422 however, and it will not latch.

The input appears as a 7pF capacitance and does not change even if the input is driven from an AC source. While the device will operate and no damage will occur up to 25V below the negative rail, input current will increase up to 1mA/V due to the clamping action of the input, ESD diode, and 1k $\Omega$  resistor.

#### **Power Dissipation**

#### CMOS circuits usually permit the user to ignore power

dissipation. Logic families such as 4000 and 74C have outputs which can only supply a few milliamperes of current, and even shorting outputs to ground will not force enough current to destroy the device. The MIC4421/4422 on the other hand, can source or sink several amperes and drive large capacitive loads at high frequency. The package power





dissipation limit can easily be exceeded. Therefore, some attention should be given to power dissipation when driving low impedance loads and/or operating at high frequency.

The supply current vs. frequency and supply current vs capacitive load characteristic curves aid in determining power dissipation calculations. Table 1 lists the maximum safe operating frequency for several power supply voltages when driving a 10,000pF load. More accurate power dissipation figures can be obtained by summing the three dissipation sources.

Given the power dissipation in the device, and the thermal resistance of the package, junction operating temperature for any ambient is easy to calculate. For example, the thermal resistance of the 8-pin plastic DIP package, from the data sheet, is 130°C/W. In a 25°C ambient, then, using a maximum junction temperature of 150°C, this package will dissipate 960mW.

Accurate power dissipation numbers can be obtained by summing the three sources of power dissipation in the device:

- Load Power Dissipation (P,)
- Quiescent power dissipation (P<sub>o</sub>)
- Transition power dissipation  $(P_{T})$

Calculation of load power dissipation differs depending on whether the load is capacitive, resistive or inductive.

#### **Resistive Load Power Dissipation**

Dissipation caused by a resistive load can be calculated as:

$$P_{1} = I^{2} R_{0} D$$

where:

- I = the current drawn by the load
- R<sub>o</sub> = the output resistance of the driver when the output is high, at the power supply voltage used. (See data sheet)
- D = fraction of time the load is conducting (duty cycle)

#### Table 1: MIC4421 Maximum Operating Frequency

| V <sub>s</sub>                     | Max Frequency |
|------------------------------------|---------------|
| 18V                                | 220kHz        |
| 15V                                | 300kHz        |
| 10V                                | 640kHz        |
| 5V                                 | 2MHz          |
| Conditions: 1. $\theta_{JA} = 150$ | )°C/W         |

2. T = 25°C

6. 
$$\hat{C_{L}} = 10,000 \text{ pF}$$

#### **Capacitive Load Power Dissipation**

Dissipation caused by a capacitive load is simply the energy placed in, or removed from, the load capacitance by the driver. The energy stored in a capacitor is described by the equation:

As this energy is lost in the driver each time the load is charged or discharged, for power dissipation calculations the 1/2 is removed. This equation also shows that it is good practice not to place more voltage in the capacitor than is necessary, as dissipation increases as the square of the voltage applied to the capacitor. For a driver with a capacitive load:

$$P_L = f C (V_S)^2$$

where:

f = Operating Frequency C = Load Capacitance  $V_s$  =Driver Supply Voltage

#### Inductive Load Power Dissipation

For inductive loads the situation is more complicated. For the part of the cycle in which the driver is actively forcing current into the inductor, the situation is the same as it is in the resistive case:

$$P_{L1} = I^2 R_0 D$$

However, in this instance the  $\rm R_o$  required may be either the on resistance of the driver when its output is in the high state, or its on resistance when the driver is in the low state, depending on how the inductor is connected, and this is still only half the story. For the part of the cycle when the inductor is forcing current through the driver, dissipation is best described as

$$P_{12} = I V_{D} (1 - D)$$

where  $V_{\rm D}$  is the forward drop of the clamp diode in the driver (generally around 0.7V). The two parts of the load dissipation must be summed in to produce  $P_{\rm I}$ 

$$P_{L} = P_{L1} + P_{L2}$$

#### **Quiescent Power Dissipation**

Quiescent power dissipation ( $P_{q}$ , as described in the input section) depends on whether the input is high or low. A low input will result in a maximum current drain (per driver) of  $\leq 0.2$ mA; a logic high will result in a current drain of  $\leq 3.0$ mA. Quiescent power can therefore be found from:

$$P_{Q} = V_{S} [D I_{H} + (1 - D) I_{L}]$$

where:

- $I_{H}$  = quiescent current with input high
- $I_{i}$  = quiescent current with input low
- $\vec{D}$  = fraction of time input is high (duty cycle)

 $V_s$  = power supply voltage

#### **Transition Power Dissipation**

Micrel, Inc.

Transition power is dissipated in the driver each time its output changes state, because during the transition, for a very brief interval, both the N- and P-channel MOSFETs in the output totem-pole are ON simultaneously, and a current is conducted through them from  $V_s$  to ground. The transition power dissipation is approximately:

$$P_{T} = 2 f V_{S} (A \cdot s)$$

where (A•s) is a time-current factor derived from the typical characteristic curve "Crossover Energy vs. Supply Voltage."

Total power  $(P_{D})$  then, as previously described is just

$$P_{D} = P_{L} + P_{Q} + P_{T}$$

Definitions

- $C_1$  = Load Capacitance in Farads.
- D = Duty Cycle expressed as the fraction of time the input to the driver is high.
- f = Operating Frequency of the driver in Hertz
- $I_{H}$  = Power supply current drawn by a driver when both inputs are high and neither output is loaded.
- $I_{L}$  = Power supply current drawn by a driver when both inputs are low and neither output is loaded.
- $I_{D}$  = Output current from a driver in Amps.
- $P_{D}$  = Total power dissipated in a driver in Watts.
- $P_L$  = Power dissipated in the driver due to the driver's load in Watts.
- $P_{o}$  = Power dissipated in a quiescent driver in Watts.
- P<sub>T</sub> = Power dissipated in a driver when the output changes states ("shoot-through current") in Watts. NOTE: The "shoot-through" current from a dual transition (once up, once down) for both drivers is stated in Figure 7 in ampere-nanoseconds. This figure must be multiplied by the number of repetitions per second (frequency) to find Watts.
- $R_0$  = Output resistance of a driver in Ohms.

 $V_s$  = Power supply voltage to the IC in Volts.

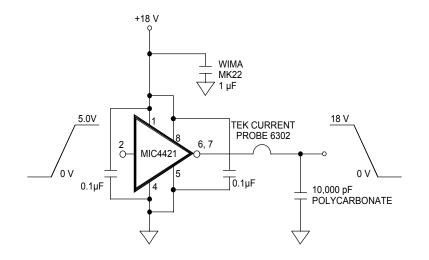
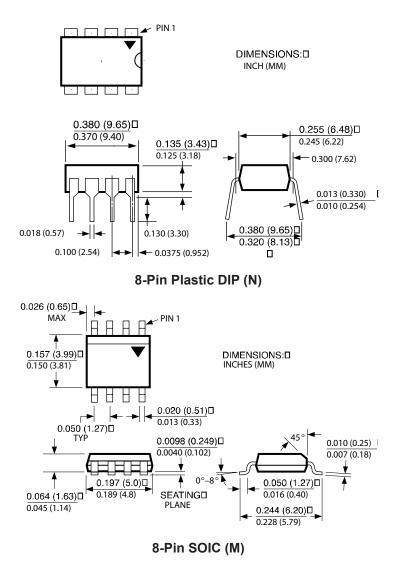
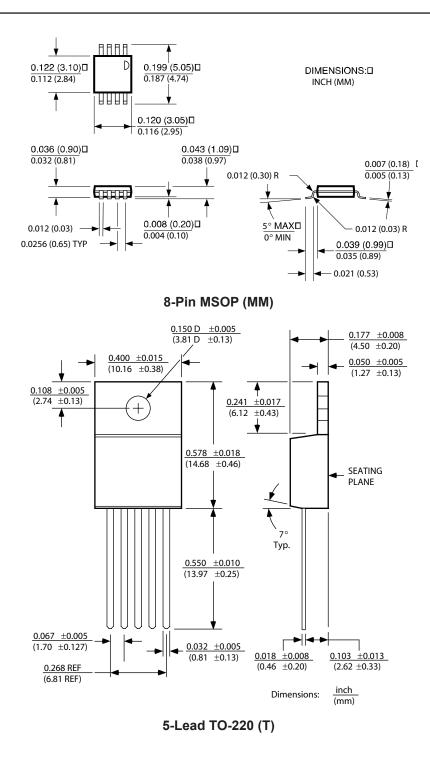


Figure 6. Peak Output Current Test Circuit

## **Package Information**





# MICREL INC. 2180 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL + 1 (408) 944-0800 FAX + 1 (408) 474-1000 WEB http://www.micrel.com

This information furnished by Micrel in this data sheet is believed to be accurate and reliable. However no responsibility is assumed by Micrel for its use. Micrel reserves the right to change circuitry and specifications at any time without notification to the customer.

Micrel Products are not designed or authorized for use as components in life support appliances, devices or systems where malfunction of a product can reasonably be expected to result in personal injury. Life support devices or systems are devices or systems that (a) are intended for surgical implant into the body or (b) support or sustain life, and whose failure to perform can be reasonably expected to result in a significant injury to the user. A Purchaser's use or sale of Micrel Products for use in life support appliances, devices or systems is a Purchaser's own risk and Purchaser agrees to fully indemnify Micrel for any damages resulting from such use or sale.

© 2004 Micrel, Inc.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Micrel:

MIC4422ZM TR

Microchip:

MIC4422YM MIC4422ZT MIC4422ZM MIC4422ZN MIC4421ZM MIC4421ZT MIC4421ZN MIC4421YN MIC4421YM MIC4421ZM-TR MIC4421YM-TR MIC4422ZM-TR